Product data sheet

1. General description

Ultrafast power diode in a SMA package.

2. Features and benefits

- Fast switching
- SMA package
- · High voltage capability
- Low forward voltage drop
- Low leakage current
- · Low thermal resistance
- · Soft recovery characteristic

3. Applications

- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)
- · Switching power supplies, inverters and as free wheeling diodes
- · High frequency switched-mode power supplies

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Values	Unit		
Absolute	Absolute maximum rating					
V_{RRM}	repetitive peak reverse voltage		600	V		
I _{F(AV)}	average forward current	δ = 0.5; square-wave pulse; $T_{lead} \le$ 140 °C; Fig. 1; Fig. 2; Fig. 3	1	A		
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t_p = 25 μs; $T_{lead} \le$ 140 °C; square-wave pulse	2	A		
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	39	Α		
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	43	Α		

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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		v 14 A
2	Α	anode	1 2	K

6. Ordering information

Table 3. Ordering information

Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
MURS160	SMA	MURS160J	Reel	7500	SMAE	03-Mar-2020

7. Marking

Table 4. Marking codes

Type number	Marking codes
MURS160	S160

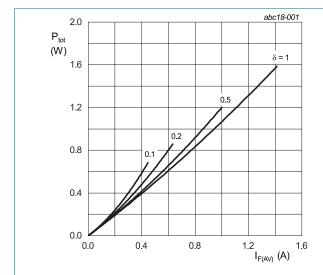
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8. Limiting values

Table 5. Limiting values

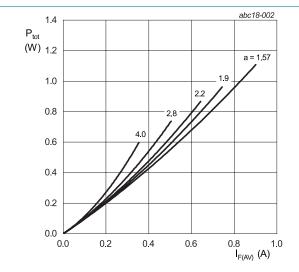
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		600	V
V_{RWM}	crest working reverse voltage		600	V
V_R	reverse voltage	DC	600	V
I _{F(AV)}	average forward current	δ = 0.5; square-wave pulse; $T_{lead} \le$ 140 °C; Fig. 1; Fig. 2; Fig. 3	1	Α
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t_p = 25 μ s; $T_{lead} \le$ 140 °C; square-wave pulse	2	Α
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	39	Α
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	43	Α
T _{stg}	storage temperature		-65 to 175	°C
T _j	junction temperature		175	°C



$$\begin{split} I_{F(AV)} &= I_{F(RMS)} \times \sqrt{\delta} \\ V_o &= 0.934 \text{ V}; \text{ R}_s = 0.1331 \text{ }\Omega \end{split}$$

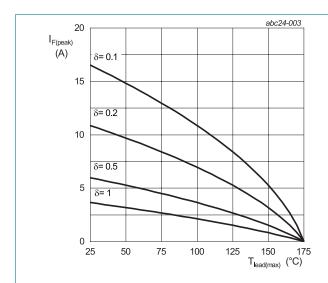
Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor = $I_{F(RMS)}/I_{F(AV)}$ V_o = 0.934 V; R_s = 0.1331 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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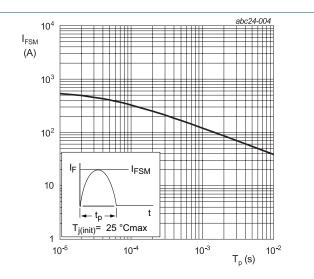


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-lead)}}$	thermal resistance from junction to lead	Fig. 5	-	-	29	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	-	216	K/W

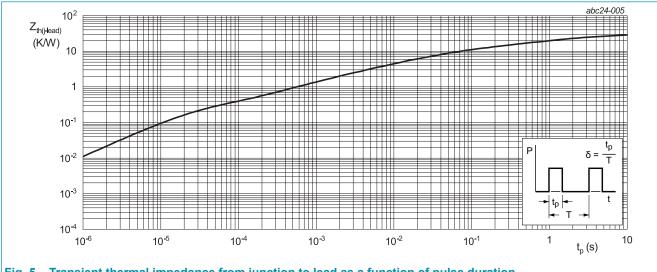


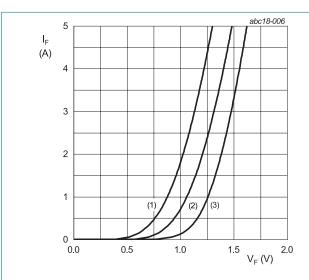
Fig. 5. Transient thermal impedance from junction to lead as a function of pulse duration

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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics					
V _F forv	forward voltage	I _F = 1 A; T _j = 25 °C	-	-	1.25	V
		I _F = 1 A; T _j = 150 °C	-	-	1.05	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C	-	-	5	μA
		V _R = 600 V; T _j = 150 °C	-	-	150	μA
Dynamic	characteristics					
Q_r	reverse charge	$I_F = 1 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/us};$ $T_j = 25 ^{\circ}\text{C}; Fig. 7$	-	45	-	nC
		$I_F = 1 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/us};$ $T_j = 125 \text{ °C}; Fig. 7$	-	81	-	nC
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A/us};$ $T_j = 25 ^{\circ}\text{C}; Fig. 7$	-	-	75	ns
		$I_F = 0.5 \text{ A}; I_R = 1 \text{ A}; I_{R(meas)} = 0.25 \text{ A};$ $T_j = 25 \text{ °C}; \text{ Step recovery}$	-	-	56	ns
		$I_F = 1 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/us};$ $T_j = 25 \text{ °C}; Fig. 7$	-	31	-	ns
		$I_F = 1 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/us};$ $T_j = 125 \text{ °C}; Fig. 7$	-	46	-	ns
I _{RM}	peak reverse recovery current	$I_F = 1 \text{ A}$; $V_R = 400 \text{ V}$; $dI_F/dt = 200 \text{ A/us}$; $T_j = 25 \text{ °C}$; Fig. 7	-	2.9	-	А
		$I_F = 1 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/us};$ $T_j = 125 \text{ °C}; Fig. 7$	-	3.5	-	А
E _{as}	non-repetitive avalanche energy	I _R = 0.9 A; L = 15 mH; T _{j(init)} = 25 °C	6	-	-	mJ



 V_o = 0.934 V; R_s = 0.1331 Ω

(1) T_j = 150 °C; typical values (2) T_j = 150 °C; maximum values

(3) T_i = 25 °C; maximum values



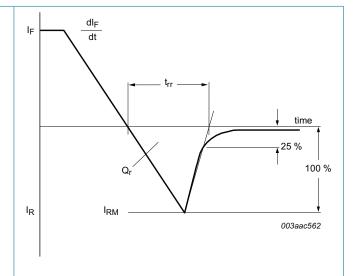


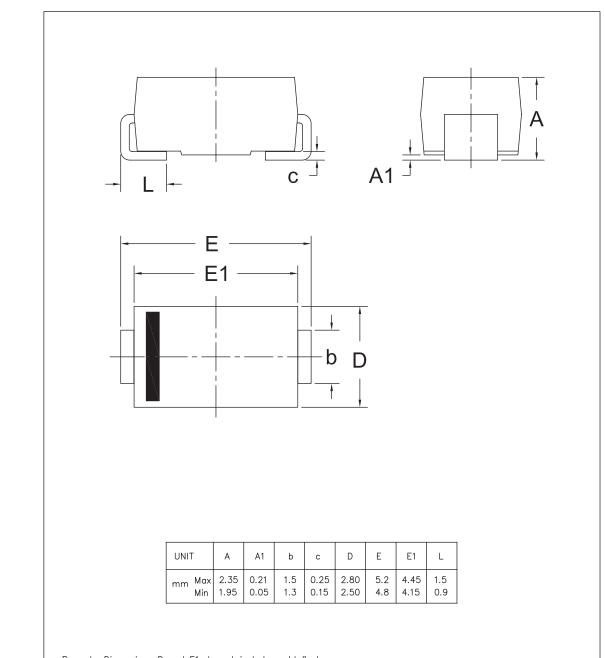
Fig. 7. Reverse recovery definitions; ramp recovery

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11. Package outline



Remark: Dimensions D and E1 do not include mold flash.

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12. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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